Atomically Resolved Single-Walled Carbon Nanotube Intramolecular Junctions

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Intramolecular junctions in single-walled carbon nanotubes are potentially ideal structures for building robust, molecular-scale electronics but have only been studied theoretically at the atomic level. Scanning tunneling microscopy was used to determine the atomic structure and electronic properties of such junctions in single-walled nanotube samples. Metal-semiconductor junctions are found to exhibit an electronically sharp interface without localized junction states, whereas a more diffuse interface and low-energy states are found in metal-metal junctions. Tight-binding calculations for models based on observed atomic structures show good agreement with spectroscopy and provide insight into the topological defects forming intramolecular junctions. These studies have important implications for applications of present materials and provide a means for assessing efforts designed to tailor intramolecular junctions for nanoelectronics.

Single-walled carbon nanotubes (SWNTs) intramolecular junctions (IMJs) formed by interposing one or multiple topologic pentagon-heptagon (5–7) defects (in the normal hexagonal structure) between two nanotube segments of different helicity have aroused substantial interest due to their potential for creating nanoelectronic devices (1–3). Theoretical studies of the electronic properties of model SWNT IMJs (4–9) suggest that these structures could function as molecular-size metal-semiconductor (M-S), metal-metal (M-M), or semiconductor-semiconductor building blocks with robust solid-state behavior. To date, experimental observations of bent SWNTs (10, 11) and transport through nanotube structures (11, 12) have provided only indirect evidence for the existence of IMJs. Atomically resolved scanning tunneling microscopy (STM), which has previously shown that SWNTs can exhibit a wide range of atomic structures (13–15), represents a potentially ideal technique for illuminating the properties of IMJs. The wide range of SWNT structures observed (15) underscores the importance in elucidating the atomic-level structure of suspected IMJs to define their existence (16) and to understand their electronic properties.

We report STM studies of SWNTs that resolve the atomic structures and electronic properties of M-S and M-M IMJs. The observed atomic structures of the SWNTs forming IMJs were used to construct atomic models of the junctions. Comparisons between tight-binding calculations and spatially resolved tunneling spectroscopy data were used to determine the most likely configurations of topological defects for IMJs and reveal characteristic features of the M-S and M-M IMJs. The ability to characterize IMJs at the atomic level will aid in further developing our understanding of these molecular-scale structures and will be critical to synthetic efforts aimed at "engineering" junctions.

A homemade ultrahigh vacuum STM operating at 5 K was used to characterize the structure and electronic properties of SWNTs. Sample preparation and image analysis were similar to previous studies (14, 17). Atomically resolved images of a large number (about 100) of individual SWNTs and SWNT bundles were recorded, and about 10% of these were found to exhibit stable defect features under extended scanning. Features that change with scanning are also observed and can be attributed to adsorbates (18).

A typical example of a SWNT IMJ (Fig. 1A), which is located at the center of the image, is visible at different bias voltages as a clear perturbation in the regular atomic-scale structure of the upper and lower portions of the SWNT. The fact that a 5-7 defect is not clearly visible in this region is not surprising because (i) the defect may not be located directly at the upper surface of the SWNT circumference and (ii) the local density of states, which are measured in the STM experiment, do not necessarily reflect the atom positions. This latter point has been addressed specifically in recent theoretical calculations of expected STM images for different 5-7 defect configurations (19–23). The presence of the IMJ is, however, demonstrated clearly by determining the SWNT structural indices, which are defined by the diameter and helicity, and the electronic properties (Fig. 1B) for the upper and lower portions of the nanotube.

Analysis of Fig. 1A shows that the upper and lower portions of the nanotube have similar diameters, 1.57 ± 0.07 nm, but significantly different in its chiral angles (θ), where the angle is defined relative to the zigzag direction, for the upper and lower portions, θ = −3.9° ± 0.8° and −10.5° ± 0.8°, respectively. The very significant change in chiral angle that occurs across the local defect is strong evidence that this feature is an IMJ. Further support for this conclusion was obtained from tunneling spectroscopy data (Fig. 1B), which show clear peaks corresponding to the van Hove singularities (VHS) characteristic of the one-dimensional SWNT (13–15). The difference between the first VHS in the upper segment, 0.45 eV, is about three times smaller than the difference for the lower segment, 1.29 eV, and is thus consistent with the upper and lower portions being semiconducting and metallic, respectively (15). That is, the gap, $E_g$, between first VHS depends only on diameter (d) and not the helicity: $E_g = G\gamma_a d^2 / G\gamma_a d^2$, where $\gamma_a$ is transfer matrix element, $d$ is the carbon-carbon bond distance, and G is 2 for semiconducting and 6 for metallic SWNTs (24). The gaps calculated using the measured diameter and our experimentally determined value of $\gamma_a = 2.5 eV$ (14, 24), 0.45 and 1.35 eV, are consistent with those measured (Fig. 1B).

We also characterized in greater detail the electronic properties of the IMJ using spatially resolved spectroscopy measurements (Fig. 1C). Examination shows that the gap defined by VHS in the semiconducting tube segment (small arrows) decays across the IMJ into the semiconducting segment within <1 nm, whereas the distinct spectroscopic features of the metallic tube (large arrows) appear to decay more quickly across the junction interface. The relatively sharp interface is consistent with theoretical calculations on model structures (5–8) and supports the idea that molecular-scale devices could be developed from SWNT IMJs. In addition, no localized states are detected in the interface region, suggesting that the M-S junction may behave as an ideal Schottky diode. These atomic-level observations lend support to recent experiments (11, 12) that have attributed IMJs to rectifying transport data.

In comparison to previous work (10–12), our atomically resolved images enable atomic models of the junction to be constructed, analyzed theoretically, and compared with the experimental spectroscopy data. To build models of the IMJ, the SWNT (n,m) indices that correspond to a specific combination of d and θ (24) were determined by using an iterative projection matching method (17). The (n,m) indices define the nanotube structure through the vector $C_n = a_1 + ma_2$, where $a_1$ and $a_2$ are the standard hexagonal basis vectors.
where \( \mathbf{a}_1 \) and \( \mathbf{a}_2 \) are the unit vectors of the graphene hexagonal lattice. For the semiconducting and metallic portions, these indices are \((21, -2)\) and \((22, -5)\), respectively. SWNT segments with these indices can be joined seamlessly along a common axis using different configurations of 5-7 defects. Two low-energy structural models are shown (Fig. 2A), which have been optimized using molecular mechanical energy minimization. Model I consists of three separated 5-7 pairs and Model II has two isolated 5-7 pairs and one 5-7/7-5 pair. It is possible to evaluate the viability of these atomic models by calculating the local electronic density of states (LDOS) and comparing these with experiment. The results from our tight-binding calculations (15, 25) (Fig. 2B) show that LDOS for Model I matches the experimental data well. Specifically, the first VHS of the semiconducting segment decays across the IMJ into the metallic segment with a decay constant similar to that in the experiment. In contrast, the LDOS calculated for Model II exhibits low-energy states around \(-0.10\) eV, which are not observed in our experimental data. Hence, we believe that Model I can be reasonably assigned to the structure for the observed IMJ. Our new results and previous calculations (5–8) show that the absence or presence of localized states at the M-S junction reflect the specific configuration of 5-7 defects. Because this could be used to vary device properties, it will be interesting to see whether these configurations can be controlled in the future.

We also characterized a M-M IMJ junction using similar methods (Fig. 3). The atomically resolved image (Fig. 3A) suggests a large difference in diameters but similar chiral angles for the upper and lower segments of IMJ structure, \( d = 1.23 \pm 0.05 \) nm and \( \theta = 24.3^\circ \pm 0.6^\circ \), and \( d = 1.06 \pm 0.05 \) nm and \( \theta = 23.8^\circ \pm 0.6^\circ \), respectively. The local spectroscopy data recorded away from the IMJ region (Fig. 3B)
demonstrates that the magnitude of the first VHS gap for the lower segment is larger than that recorded on the upper segment. Thus, these gaps are consistent with the diameters determined from the images. Moreover, they show that both segments are metallic SWNTs. In addition, spatially resolved spectroscopy data recorded across the IMJ (Fig. 3C) shows new features not observed in the M-S IMJ discussed above; that is, there are low-energy peaks at –0.55 and –0.27 eV not present in the spectroscopy data recorded away from the junction. These peaks appear to decay slowly from the IMJ into the bulk of the larger diameter segment but quickly into the smaller segment.

We determined the (n,m) indices of the larger and smaller segments of the IMJ structure using the iterative method above and find the best fits to be for values of (11,8) and (9,6), respectively, which are both metallic tubes. To check the consistency of this assignment, tight-binding calculations were used to evaluate the LDOS for isolated (11,8) and (9,6) tubes. Comparison of the calculated and experimental LDOS (Fig. 3B) shows excellent agreement and substantiates our assignment of the indices and the M-M character of the junction. The (11,8) and (9,6) SWNT segments can be joined seamlessly along a common axis using different configurations of 5-7 defects. A specific model demonstrated unambiguously that IMJs are present in SWNT samples, and statistics show the common occurrence of these defects could have important implications for the interpretation of electrical transport and mechanical measurements. These studies provide experimentally derived atomic-level junction models that will enable an important dialog between experiments and further high-level calculations designed to reveal details of IMJ physics. We also believe that STM characterization of IMJs can
provide critical information and a feedback mechanism for growth studies designed to establish rational pathways for controllably producing IMFs in the future.

References and Notes

Evidence for Coherent Proton Tunneling in a Hydrogen Bond Network

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We observed coherent proton tunneling in the cyclic network of four hydrogen bonds in calix[4]arene. The tunneling frequency of 35 megahertz was revealed by a peak in the magnetic field dependence of the proton spin-lattice relaxation rate measured with field-cycling nuclear magnetic resonance in the solid state at temperatures below 80 kelvin. The amplitude of the coherent tunneling peak grows with temperature according to the Boltzmann law with energy $D/k_B = (125 \pm 10)$ kelvin (where $k_B$ is Boltzmann’s constant). The tunneling peak can be interpreted in the context of level crossings in the region where the tunneling frequency matches the proton Larmor frequency. The tunneling spectrum reveals fine structure that we attribute to coupling between the hydrogen bonds in the network. The characteristics of the tunneling peak are interpreted in the context of the potential energy surface experienced by the hydrogen atoms in the network.

Quantum tunneling can occur when a particle with energy $E$ encounters a potential barrier of magnitude $V_0$ greater than $E$. The tunneling probability that defines the tunneling frequency is an exponential function of the barrier properties and the particle mass, and so observations of tunneling are usually confined to particles of low mass that move over short distances.

The explicit observation of molecular tunneling has been confined to relatively few systems. For example, the rotation of symmetrical groups at low temperature and, in the life sciences, evidence for the role of hydrogen tunneling in enzyme catalysis has recently been revealed through the effects of the atomic mass on the rates of reaction by isotopic substitution ($I$, $J$).

Here we report the direct observation of coherent tunneling associated with proton transfer among a network of four coupled hydrogen (H) bonds in which the proton motion exhibits an oscillatory motion with a well-defined frequency. The coupling between H bonds also manifests itself in fine structure. These observations not only provide an example of coherent translational tunneling but also promise to reveal insight into the fundamental mechanisms of chemical reactions.

In selecting molecules with structural properties that are liable to reveal coherent tunneling, it is important to identify structures that, in the isolated molecule at least, have degenerate tautomers that can interconvert by proton motion. To minimize coupling to the environment that would otherwise quench the oscillatory modes, the energy asymmetry of the tautomers, which can then only arise from the interactions between molecules in the solid state, must be small. Calix[n]arenes can meet this requirement; they are bowl-shaped macromolecules with ordered arrays of phenol-methylene oligomers (3). We studied one of the simplest members of this family, calix[4]arene (Fig. 1). The molecule has fourfold symmetry, and its shape is maintained by a cyclic network of four intramolecular H bonds at its base. There are no intermolecular H bonds. We can identify two degenerate tautomers of the isolated molecule that are related by proton transfer among the four H bonds.

Nuclear magnetic resonance (NMR) relaxometry is well established for studying molecular dynamics. Atomic motion modulates the dipole-dipole interaction between nuclei and, indirectly, drives the population changes in the nuclear spin levels that give rise to spin-lattice relaxation. As the dipolar interaction has nuclear spin operators that involve spin-lattice relaxation, As the dipolar interaction has nuclear spin operators that involve spin-lattice relaxation, As the dipolar interaction has nuclear spin operators that involve spin-lattice relaxation, As the dipolar interaction has nuclear spin operators that involve spin-lattice relaxation, As the dipolar interaction has nuclear spin operators that involve spin-lattice relaxation, As the dipolar interaction has nuclear spin operators that involve spin-lattice relaxation.

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$$J(t) = \int \langle F^{(n)}(t + \tau) F^{(m)}(t) \rangle \exp(i\omega t) d\tau \tag{1}$$

where $\omega$ is Planck’s constant divided by $\pi$. The spectral density, $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$, is the Fourier transform of the dipolar correlation function: $J(\omega)$.